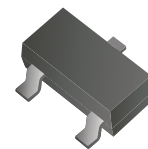


CDBT-70/S/C/A-G

Reverse Voltage: 70 Volts
Forward Current: 70 mA
RoHS Device



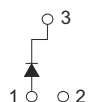
Features

- Design for mounting on small surface.
- High speed switching application, circuit protection.
- Low turn-on voltage.

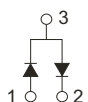
Mechanical data

- Case: SOT-23, molded plastic.
- Terminals: solderable per MIL-STD-750, method 2026.
- Approx. weight: 0.008 grams

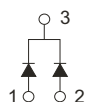
Circuit diagram



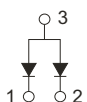
CDBT-70-G



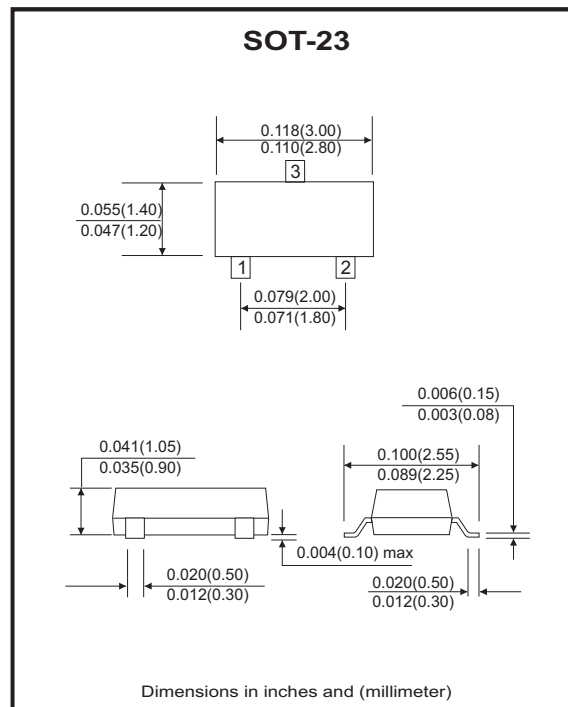
CDBT-70S-G



CDBT-70C-G



CDBT-70A-G



Maximum Ratings and Electrical Characteristics

(at Ta=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Value	Units
Repetitive peak reverse voltage	V_{RRM}		70	V
Reverse voltage	V_R		70	V
Forward continuous current	I_F		70	mA
Non-Repetitive peak forward surge current	I_{FSM}	T=1.0 sec	100	mA
Power dissipation	P_D		200	mW
Maximum forward voltage	V_F	@ $I_F=1.0mA$ @ $I_F=15mA$	410 1000	mV
Maximum reverse leakage current	I_R	@ $V_R=50V$	100	nA
Maximum reverse recovery time	T_{rr}	$I_F=I_R=10mA, R_L=100\Omega, I_{rr}=0.1*I_R$	5	nS
Maximum diode capacitance	C_D	$V_R=0V, f=1.0MHz$	2	pF
Thermal Resistance Junction to Ambient	$R_{\theta JA}$		500	°C/W
Junction temperature	T_J		125	°C
Storage temperature	T_{STG}		-55 to +150	°C

Company reserves the right to improve product design, functions and reliability without notice.

REV:B

RATING AND CHARACTERISTIC CURVES (CDBT-70/S/C/A-G)

Fig.1 - Forward Characteristics

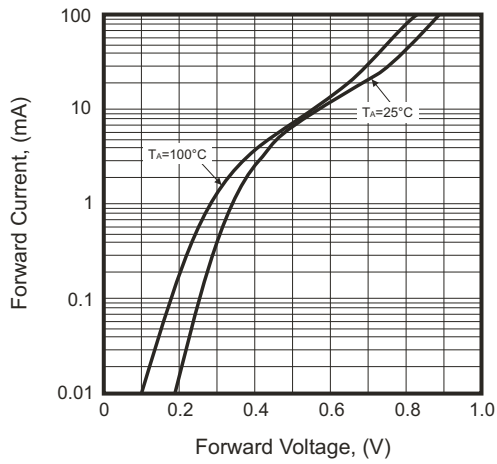


Fig.2 - Reverse Characteristics

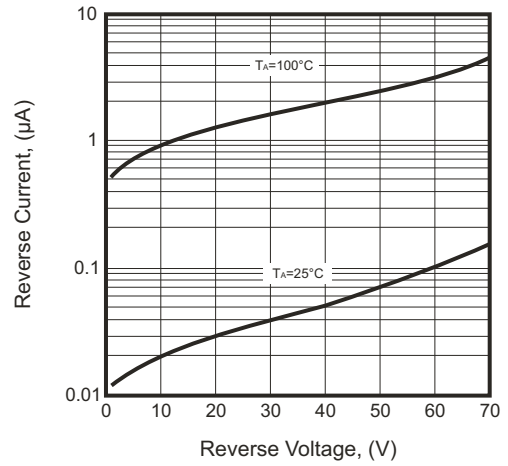


Fig.3 - Capacitance Characteristics

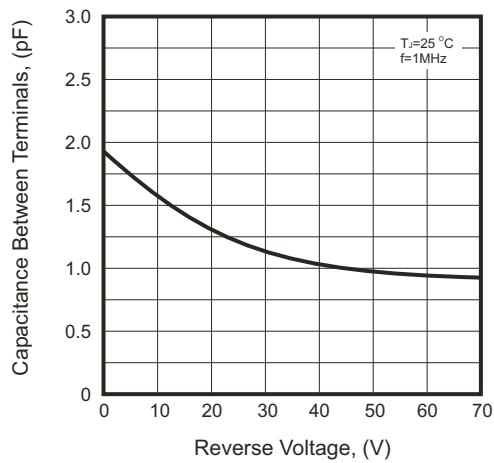


Fig.4 - Power Derating Curve

